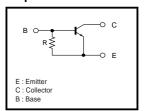
Digital transistors (built-in resistor) DTC115GUA / DTC115GKA / DTC115GSA

Features

- The built-in bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input, and parasitic effects are almost completely eliminated.
- 2) Only the on / off conditions need to be set for operation, making device design easy.
- 3) Higher mounting densities can be achieved.

●Equivalent circuit



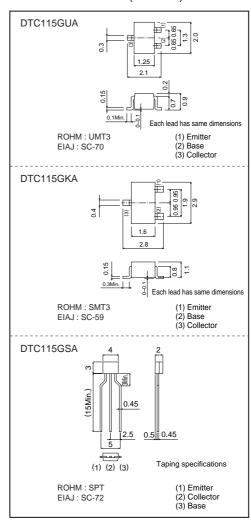
● Absolute maximum ratings (Ta=25°C)

| Parameter | | Symbol | Limits | Unit |
|-----------------------------|-----------------------|--------|-------------|------|
| Collector-base voltage | | Vсво | 50 | V |
| Collector-emitter voltag | | VCEO | 50 | V |
| Emitter-base voltage | | VEBO | 5 | V |
| Collector current | | Ic | 100 | mA |
| Collector power dissipation | DTA115GUA / DTA115GKA | Pc | 200 | mW |
| | DTA115GSA | PC | 300 | mW |
| Junction temperature | | Tj | 150 | °C |
| Storage temperature | | Tstg | -55 to +150 | ° |

Package, marking, and packaging specifications

| Туре | DTC115GUA | DTC115GKA | DTC115GSA |
|------------------------------|-----------|-----------|-----------|
| Package | UMT3 | SMT3 | SPT |
| Marking | K29 | K29 | - |
| Packaging code | T106 | T146 | TP |
| Basic ordering unit (pieces) | 3000 | 3000 | 5000 |

●External dimensions (Unit: mm)



●Electrical characteristics (Ta=25°C)

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions |
|--------------------------------------|----------|------|------|------|------|------------------------------|
| Collector-base breakdown voltage | ВУсво | 50 | - | - | V | Ic=50μA |
| Collector-emitter breakdown voltag | BVceo | 50 | - | - | V | Ic=1mA |
| Emitter-base breakdown voltage | ВУево | 5 | - | - | V | Iε=72μA |
| Collector cutoff current | Ісво | - | - | 0.5 | μА | Vcb=50V |
| Emitter cutoff current | ІЕВО | 30 | - | 58 | μА | V _{EB} =4V |
| Collector-emitter saturation voltage | VcE(sat) | - | - | 0.3 | V | Ic=5mA, Is=0.25mA |
| DC current transfer ratio | hre | 82 | - | - | - | Ic=5mA, VcE=5V |
| Emitter-base resistance | R | 70 | 100 | 130 | kΩ | = |
| Transition frequency | fτ | - | 250 | - | MHz | Vce=10V, Ie=-5mA, f=100MHz * |

Transition frequency of the device

•Electrical characteristics curves

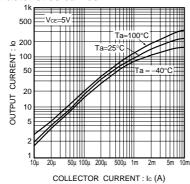


Fig.1 DC current transfer ratio vs. collector current characteristics

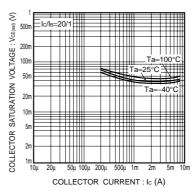


Fig.2 Collector-emitter saturation voltage vs. collector current characteristics

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